



ACT Node Standard Recipes

Resist	ZEP 520A	Sample Prep for Resist spin	
Tone	Positive Tone Resist	Cleaning Solution	Sonicate
Solid content	11%	Acetone	2~5 min
Developer	ZED N50- (n Amyl Acetate)	IPA	2~5 min
Stopper	ISO-Propanol	Ethanol (optional)	2~5 min
Remover	ZDMAC- (Di-Methyl Acetamide)	DI Water Rinse	2~5 min
Thinner	Anisole	Bake (Hotplate)	5 min

Spin	Speed	Thickness	Time
	4000rpm	350~380nm	60 s
Pre-Bake	Temperature		
	180 °C	if Hot Plate used	2 min
	180 °C	if oven used	30 min
Exposure	Voltage	Base Dose	
	20kV	35 uC/cm ²	
Develop	ZEP Developer	Dipping	1 min
Stopper	IPA	Dipping	30 ~ 60 s
Rinse	DI water	Dip and Stir	30 s
Post Bake	Temperature	before etch (if required)	
	140 °C	Hot Plate	2 min
	140 °C	Oven	25 min
Remover	ZEP Remover	Time depends on the patterns and thickness of resist	Soak for 30 ~ 40 min or more
		DI Water rinse	1 min

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